
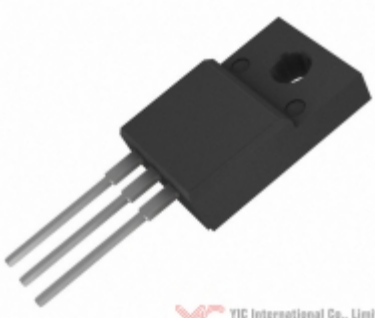
	<h2 style="color: red;">FQPF11P06</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">FQPF11P06</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 60V 8.6A TO-220F</p> <p><b>Datenblätter:</b>  <a href="#">FQPF11P06.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 87527 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQPF11P06</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET P-CH 60V 8.6A TO-220F
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	87527 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3 Full Pack
Supplier Device-Gehäuse	TO-220F
Verlustleistung (max)	30W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.6A (Tc)
Rds On (Max) @ Id, Vgs	175 mOhm @ 4.3A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	550pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube













































FQPF11P06 ist neu im Original, Suche FQPF11P06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQPF11P06 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQPF11P06: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQPF11N60C</b> FAIRCHILD FQPF11N60C FAIRCHILD</p>	 <p><b>FQPF12N60</b> Fairchild/ON Semiconductor MOSFET N-CH 600V 5.8A TO-220F</p>	 <p><b>FQPF11P06</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 8.6A TO-220F</p>	 <p><b>FQPF11N50CF</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 11A TO-220F</p>
 <p><b>FQPF11N60</b> VB FQPF11N60 VB</p>	 <p><b>FQPF12N60</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 5.8A TO-220F</p>	 <p><b>FQPF12N50</b> Original FQPF12N50 Original</p>	 <p><b>FQPF12N50C</b> Original FQPF12N50C Original</p>

### heiße Teile

Mehr

 FQP9N65C	 FQP9N90C	 FQP9N90C	D FQPF10N20	 FQPF10N20
 FQPF10N20C	 FQPF10N20C	D FQPF10N50CF	 FQPF10N50CF	 FQPF10N60
 FQPF10N60C	 FQPF10N60C	 FQPF10N60CF	 FQPF10N60CF	 FQPF10N65C
D FQPF11N40	 FQPF11N40C	 FQPF11N40C	 FQPF11N50C	 FQPF11N50CF
 FQPF11N50CF	 FQPF11N60	 FQPF11N60C	 FQPF11N65C	 FQPF11P06
 FQPF12N50C	 FQPF12N60C	D FQPF12N60C	 FQPF12N60CG	 FQPF12N60CT
 FQPF12N60CT	D FQPF12N65C	 FQPF12N80	 FQPF12P10	 FQPF12P10
 FQPF12P20	 FQPF12P20	 FQPF13N06	 FQPF13N06	 FQPF13N06L
 FQPF13N06L	 FQPF13N10	 FQPF13N10	D FQPF13N50C	 FQPF13N50C
 FQPF13N50CF	 FQPF13N50CF	 FQPF13N60C	 FQPF14N15	 FQPF14N15

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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